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APPLICATION NO.	D. FILING DATE FIRST NAMED INVENTOR		ATTORNEY DOCKET NO. CONFIRMATION		
10/604,533	07/29/2003	Joachim Nuetzel	FIS920020132US1	1532	
29371 7	590 08/08/2006		EXAMINER		
	DLBURN LLP - IBM	MITCHELL, JAMES M			
55 GRIFFIN R BLOOMFIELI		ART UNIT	PAPER NUMBER		
	, 01 0000		2813		
			DATE MAILED: 08/08/2006	5	

Please find below and/or attached an Office communication concerning this application or proceeding.

		Applicat	ion No.	Applicant(s)				
Office Action Summary		10/604,5	533	NUETZEL ET AL				
		Examine	er	Art Unit				
_		James M	l. Mitchell	2813				
Period for	- The MAILING DATE of this communicate Reply	tion appears on th	e cover sheet with t	he correspondence a	ddress			
WHIC - Extens after S - If NO - Failure Any re	PRTENED STATUTORY PERIOD FOR HEVER IS LONGER, FROM THE MAIL sions of time may be available under the provisions of 3 bix (6) MONTHS from the mailing date of this communic period for reply is specified above, the maximum statuto to reply within the set or extended period for reply will, apply received by the Office later than three months after the patent term adjustment. See 37 CFR 1.704(b).	ING DATE OF T 7 CFR 1.136(a). In no e ation. ry period will apply and v by statute, cause the ap	HIS COMMUNICAT vent, however, may a reply l will expire SIX (6) MONTHS plication to become ABAND	TION. De timely filed from the mailing date of this of ONED (35 U.S.C. § 133).				
Status								
1) 🛛	Responsive to communication(s) filed o	n 15 January 20	06					
·	Responsive to communication(s) filed on <u>15 January 2006</u> . This action is FINAL . 2b)⊠ This action is non-final.							
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· —	closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.							
Dispositio	on of Claims							
4)🛛	4)⊠ Claim(s) <u>1-15</u> is/are pending in the application.							
· ·	4a) Of the above claim(s) is/are withdrawn from consideration.							
	Claim(s) is/are allowed.							
· · · · · · · · · · · · · · · · · · ·	☑ Claim(s) <u>1,5,10 and 14</u> is/are rejected.							
7)🖾	Claim(s) <u>2-4,6-9,11-13 and 15</u> is/are objected to.							
8) 🗌 (Claim(s) are subject to restriction and/or election requirement.							
Application	on Papers							
9)□ T	The specification is objected to by the E	xaminer.						
10)☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.								
	Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).							
	Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).							
11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.								
Priority u	nder 35 U.S.C. § 119							
	Acknowledgment is made of a claim for All b) Some * c) None of:	foreign priority ur	nder 35 U.S.C. § 11	9(a)-(d) or (f).				
•	1. Certified copies of the priority documents have been received.							
	2. Certified copies of the priority documents have been received in Application No							
,	3. Copies of the certified copies of the	•		eived in this National	Stage			
	application from the International	•	` ''					
* Se	ee the attached detailed Office action fo	or a list of the cer	lified copies not rece	eived.				
A44 - 1								
Attachment(s) of References Cited (PTO-892)		4) Interview Sumn	220/ (PTO 442)				
	of Draftsperson's Patent Drawing Review (PTO-	948)	Paper No(s)/Ma	il Date				
	ation Disclosure Statement(s) (PTO-1449 or PTC No(s)/Mail Date	D/SB/08)	5) Notice of Inform 6) Other:	al Patent Application (PT	O-152)			

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DETAILED ACTION

This office action is in response to applicant's amendment filed March 27, 2006.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 1, 5, 10 and 14 are rejected under 35 U.S.C. 102(e) as being anticipated by Parks et al. (U.S. 2005/0036399).

Parks (Fig. 7-9) discloses:

(cl. 1, 10) a method of forming an interconnect structure in a magnetic random access memory (MRAM) device, the methods comprising: defining a magnetic stack layer (142) on a lower metallization level (141b), said magnetic stack layer including a non-ferromagnetic layer (143) disposed between a pair of ferromagnetic layers (144,142); defining a conductive hard mask (145; Par. 0041) over said magnetic stack layer; and removing portions of said hardmask and said stack layer (Fig. 7-8), thereby creating an array of magnetic tunnel junction (MTJ) stack including remaining portions of the stack and hard mask; wherein the hardmask forms self aligning contact between said stack layer and an upper metallization level subsequently formed above said MTJ stack (150); (cl. 5, 14) wherein said hardmask is tantalum (Par. 0041).

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Claims 1, 5, 10 are rejected under 35 U.S.C. 102(e) as being anticipated by Kishl et al. (U.S.2005/0078417).

Kishl (Fig. 34A-35B, 36A-37B) discloses:

(cl. 1, 10) a method of forming an interconnect structure in a magnetic random access memory (MRAM) device, the methods comprising: defining a magnetic stack layer (see lower layer 173, not labeled; Par. 0127) on a lower metallization level (172), said magnetic stack layer including a non-ferromagnetic layer disposed between a pair of ferromagnetic layers; defining a conductive hard mask (174) over said magnetic stack layer; and removing portions of said hardmask and said stack layer (Fig. 34A-36A), thereby creating an array of magnetic tunnel junction (MTJ) stack including remaining portions of the stack and hard mask; wherein the hardmask forms self aligning contact between said stack layer and an upper metallization level subsequently formed above said MTJ stack (172);

(cl. 5, 14) wherein said hardmask is tantalum (Par. 0150);

Allowable Subject Matter

Claims 2-4, 6-9, 11-13 and 15 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

The following is a statement of reasons for the indication of allowable subject matter: while forming holes in insulation layers are known to connect to MTJ as

evidenced by for example Okazawa et al. (U.S 2002/0155627), the prior art fails to disclose or make obvious forming holes in an insulation over a MTJ including a hardmask and cap, wherein the cap is removed and an upper metallization is formed connected to the MTJ through the conductive hardmask including all the limitations of the independent claim.

Response to Arguments

Applicant's arguments with respect to claims have been considered but are moot in view of the new ground(s) of rejection.

Conclusion

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. The prior art discloses the use of forming MTJ stack including a mask, and the use of interconnecting MTJ stacks to an upper metallization level.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to James M. Mitchell whose telephone number is (571) 272-1931. The examiner can normally be reached on M-F 8:00-4:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Carl Whitehead Jr. can be reached on (571) 272-1702. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Jmm,/J.D July/28, 2006

CARL WIGHTENERD, JR.
SUPERVISORY PATENT EXAMINE

TECHNOLOGY CENTER 2800